| L Number | Hits | Search Text | DB | Time stamp |
|---|---|---|---|---|
| 1 | 1446 | high-voltage NEAR circuit$1 | USPAT; US-PGPUB; EPO; JPO; IBM_TDB | 2002/11/15 12:06 |
| 2 | 531 | (high-voltage NEAR circuit$1) and transistor | USPAT; US-PGPUB; EPO; JPO; IBM_TDB | 2002/11/15 12:06 |
| 3 | 256 | ((high-voltage NEAR circuit$1) and transistor) and ((input output) NEAR terminal$) | USPAT; US-PGPUB; EPO; JPO; IBM_TDB | 2002/11/15 12:07 |
| 4 | 239 | (((high-voltage NEAR circuit$1) and transistor) and ((input output) NEAR terminal$)) and (source darin gate) | USPAT; US-PGPUB; EPO; JPO; IBM_TDB | 2002/11/15 12:07 |
| 5 | 104 | ((((high-voltage NEAR circuit$1) and transistor) and ((input output) NEAR terminal$)) and (source darin gate)) and ((first second third) NEAR voltage) | USPAT; US-PGPUB; EPO; JPO; IBM_TDB | 2002/11/15 12:37 |
| 6 | 1137 | 330/253.ccls. | USPAT; US-PGPUB; EPO; JPO; IBM_TDB | 2002/11/15 12:37 |
| 7 | 175 | 330/253.ccls. and (high-voltage (high NEAR voltage)) | USPAT; US-PGPUB; EPO; JPO; IBM_TDB | 2002/11/15 13:26 |
| 8 | 0 | (330/253.ccls. and (high-voltage (high NEAR voltage))) and (sourece NEAR2 drain NEAR2 gate) | USPAT; US-PGPUB; EPO; JPO; IBM_TDB | 2002/11/15 12:40 |
| 9 | 57 | (330/253.ccls. and (high-voltage (high NEAR voltage))) and (source NEAR2 drain NEAR2 gate) | USPAT; US-PGPUB; EPO; JPO; IBM_TDB | 2002/11/15 13:26 |
| 10 | 172 | (330/253.ccls. and (high-voltage (high NEAR voltage))) and amplifier$1 | USPAT; US-PGPUB; EPO; JPO; IBM_TDB | 2002/11/15 13:09 |
| 11 | 142 | ((330/253.ccls. and (high-voltage (high NEAR voltage))) and amplifier$1) and terminal$1 | USPAT; US-PGPUB; EPO; JPO; IBM_TDB | 2002/11/15 12:58 |
| 12 | 142 | (((330/253.ccls. and (high-voltage (high NEAR voltage))) and amplifier$1) and terminal$1) and (input output) | USPAT; US-PGPUB; EPO; JPO; IBM_TDB | 2002/11/15 12:58 |
| 13 | 142 | ((((330/253.ccls. and (high-voltage (high NEAR voltage))) and amplifier$1) and terminal$1) and (input output)) and voltage$1 | USPAT; US-PGPUB; EPO; JPO; IBM_TDB | 2002/11/15 12:59 |
| 14 | 2 | (((((330/253.ccls. and (high-voltage (high NEAR voltage))) and amplifier$1) and terminal$1) and (input output)) and voltage$1) and (field ADJ transistor) | USPAT; US-PGPUB; EPO; JPO; IBM_TDB | 2002/11/15 13:09 |
| 15 | 9 | 330/253.ccls. and (field ADJ transistor) | USPAT; US-PGPUB; EPO; JPO; IBM_TDB | 2002/11/15 13:05 |
| 16 | 51 | 330/$.ccls. and (field ADJ transistor) | USPAT; US-PGPUB; EPO; JPO; IBM_TDB | 2002/11/15 13:05 |

| 17 | 8645 | 257/$.ccls. and amplifier$1 | USPAT; US-PGPUB; EPO; JPO; IBM_TDB | 2002/11/15 13:16 |
|---|---|---|---|---|
| 18 | 86 | (257/$.ccls. and amplifier$1) and (field ADJ transistor) | USPAT; US-PGPUB; EPO; JPO; IBM_TDB | 2002/11/15 13:17 |
| 19 | 96 | 257/368.ccls. and amplifier$1 | USPAT; US-PGPUB; EPO; JPO; IBM_TDB | 2002/11/15 13:24 |
| 20 | 1 | (257/368.ccls. and amplifier$1) and (field ADJ transistor) | USPAT; US-PGPUB; EPO; JPO; IBM_TDB | 2002/11/15 13:17 |
| 21 | 90 | (257/368.ccls. and amplifier$1) and transistor$1 | USPAT; US-PGPUB; EPO; JPO; IBM_TDB | 2002/11/15 13:17 |
| 22 | 88 | (field ADJ transistor) same amplifier$1 | USPAT; US-PGPUB; EPO; JPO; IBM_TDB | 2002/11/15 13:25 |
| 23 | 357 | (field ADJ transistor) and amplifier$1 | USPAT; US-PGPUB; EPO; JPO; IBM_TDB | 2002/11/15 13:25 |
| 24 | 137 | ((field ADJ transistor) and amplifier$1) and (high-voltage (high NEAR voltage)) | USPAT; US-PGPUB; EPO; JPO; IBM_TDB | 2002/11/15 13:26 |
| 25 | 46 | (((field ADJ transistor) and amplifier$1) and (high-voltage (high NEAR voltage))) and (source NEAR2 drain NEAR2 gate) | USPAT; US-PGPUB; EPO; JPO; IBM_TDB | 2002/11/15 13:26 |